







IF1320 N-Channel JFET

Features

InterFET N0132L Geometry
Low Noise: 1.0 nV/VHz Typical

High Gain: 22mS TypicalLow Cutoff Voltage: 1.5V Maximum

RoHS Compliant

• SMT, TH, and Bare Die Package options.

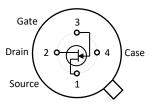
Applications

- Audio Amplifiers
- · Low Noise High Gain Amplifier

Description

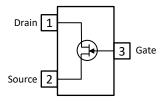
The -20V InterFET IF1320 JFET is targeted for sensitive amplifier stages for mid-frequencies designs. The IF1320 has a cutoff voltage of less than 1.5V ideal for low-level power supplies. The TO-72 package is hermetically sealed and suitable for military applications.

TO-72 Bottom View





SOT23 Top View





Product Summary

| - round out minut | | | | | | |
|----------------------|------------------------------------|------------|------|--|--|--|
| | Parameters | IF1320 Min | Unit | | | |
| BV _{GSS} | Gate to Source Breakdown Voltage | -20 | V | | | |
| I _{DSS} | Drain to Source Saturation Current | 5 | mA | | | |
| V _{GS(off)} | Gate to Source Cutoff Voltage | -0.35 | V | | | |
| GFS | Forward Transconductance | 15 | mS | | | |

Ordering Information Custom Part and Binning Options Available

| Part Number | Description | Case | Packaging |
|-------------|--|-------|----------------------|
| IF1320T72 | Through-Hole | TO-72 | Bulk |
| IF1320ST3 | Surface Mount | SOT23 | Bulk |
| | 7" Tape and Reel: 1,000 and 3,000 Pieces | | Minimum 1,000 Pieces |
| IF1320ST3TR | 13" Tape and Reel: 9,000 Pieces | SOT23 | Tape and Reel |
| IF1320COT | Chip Orientated Tray (COT Waffle Pack) | COT | 400/Waffle Pack |
| IF1320CFT | Chip Face-up Tray (CFT Waffle Pack) | CFT | 400/Waffle Pack |



Disclaimer: It is the Buyers responsibility for designing, validating and testing the end application under all field use cases and extreme use conditions. Guaranteeing the application meets required standards, regulatory compliance, and all safety and security requirements is the responsibility of the Buyer. These resources are subject to change without notice.









Electrical Characteristics

Maximum Ratings (@ T_A = 25°C, Unless otherwise specified)

| | Parameters | Value | Unit |
|------------------|--|------------|-------|
| V_{RGS} | Reverse Gate Source and Gate Drain Voltage | -20 | V |
| I _{FG} | Continuous Forward Gate Current | 10 | mA |
| PD | Continuous Device Power Dissipation | 225 | mW |
| Р | Power Derating | 1.8 | mW/°C |
| Tı | Operating Junction Temperature | -55 to 125 | °C |
| T _{STG} | Storage Temperature | -65 to 200 | °C |

Static Characteristics (@ TA = 25°C, Unless otherwise specified)

| | Parameters | Conditions | Min | Тур | Max | Unit |
|----------------------|---------------------------------------|--|-------|-----|------|------|
| V _{(BR)GSS} | Gate to Source Breakdown Voltage | $I_G = -1\mu A$, $V_{DS} = 0V$ | -20 | | | V |
| I _{GSS} | Gate to Source Reverse Current | V _{DS} = 0V, V _{GS} = -10V | | | -0.1 | nA |
| V _{GS(OFF)} | Gate to Source Cutoff Voltage | V _{DS} = 10V, I _D = 0.5 nA | -0.35 | | -1.5 | V |
| I _{DSS} | Drain to Source Saturation Current | $V_{DS} = 10V$, $V_{GS} = 0V$ (Pulsed) | 5 | 10 | | mA |

Dynamic Characteristics (@ TA = 25°C, Unless otherwise specified)

| | Parameters | Conditions | Min | Тур | Max | Unit |
|------|---|--|-----|-----|-----|--------|
| GFS | Forward Transconductance | $V_{DS} = 10V$, $I_D = 5$ mA, f = 1kHz | 15 | 22 | | mS |
| Ciss | Input Capacitance | $V_{DS} = 10V$, $I_D = 5$ mA, f = 1MHz | | | 20 | pF |
| Crss | Reverse Transfer Capacitance | $V_{DS} = 10V$, $I_D = 5$ mA, f = 1MHz | | | 5 | pF |
| en | Equivalent Circuit Input Noise Voltage | $V_{DS} = 10V$, $I_D = 5$ mA, f = 1kHz | | 1.0 | | nV/√Hz |

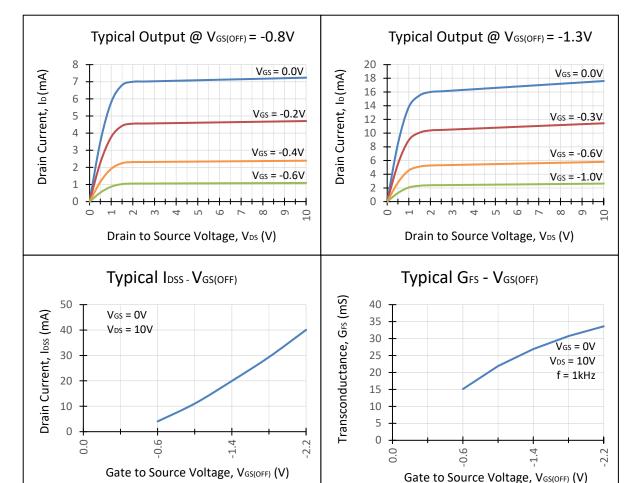








Typical IF1320 Characteristics



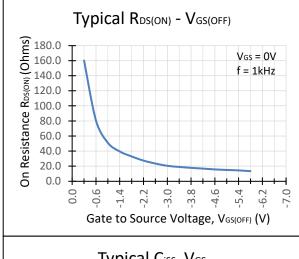


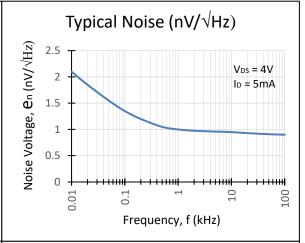


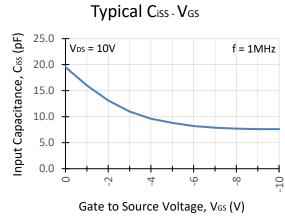


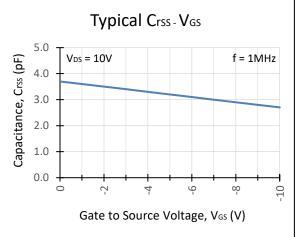


Typical IF1320 Characteristics (Continued)











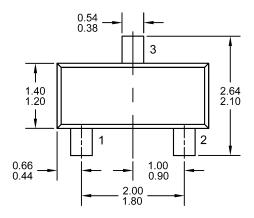


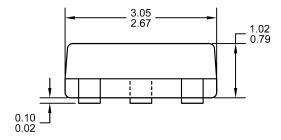


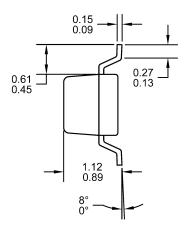


SOT23 (TO-236AB) Mechanical and Layout Data

Package Outline Data

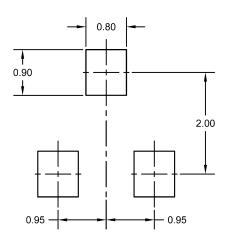






- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.12 grams
- 3. Molded plastic case UL 94V-0 rated
- For Tape and Reel specifications refer to InterFET CTC-021 Tape and Reel Specification, Document number: IF39002
- Bulk product is shipped in standard ESD shipping material
- 6. Refer to JEDEC standards for additional information.

Suggested Pad Layout



- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided for reference only. A more robust pattern may be desired for wave soldering.